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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

Details

Product Status	Not For New Designs
Core Processor	ARM® Cortex®-M3
Core Size	32-Bit Single-Core
Speed	80MHz
Connectivity	I ² C, IrDA, SmartCard, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, DMA, I ² S, POR, PWM, WDT
Number of I/O	28
Program Memory Size	32KB (32K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	8K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.6V
Data Converters	A/D 18x12b; D/A 2x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	40-VFQFN Exposed Pad
Supplier Device Package	40-QFN (6x6)
Purchase URL	https://www.e-xfl.com/product-detail/silicon-labs/sim3c134-b-gmr

Email: info@E-XFL.COM

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Table 3.2. Power Consumption (Continued)

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Power Mode 9 ^{2,3} —Low Power Shutdown with VREG0 disabled,	I _{DD}	RTC Disabled, V _{DD} = 1.8 V, T _A = 25 °C	_	85	_	nA
powered through VDD and VIO		RTC w/ 16.4 kHz LFO, V _{DD} = 1.8 V, T _A = 25 °C		350		nA
		RTC w/ 32.768 kHz Crystal, V _{DD} = 1.8 V, T _A = 25 °C		620		nA
		RTC Disabled, V _{DD} = 3.0 V, T _A = 25 °C	_	145	_	nA
		RTC w/ 16.4 kHz LFO, V _{DD} = 3.0 V, T _A = 25 °C		500	_	nA
		RTC w/ 32.768 kHz Crystal, V _{DD} = 3.0 V, T _A = 25 °C		800	_	nA
Power Mode 9 ^{2,3} —Low Power Shutdown with VREG0 in Iow-	I _{VREGIN}	RTC Disabled, VREGIN = 5 V, T _A = 25 °C	_	300		nA
ered through VREG0 (Includes VREG0 current)		RTC w/ 16.4 kHz LFO, VREGIN = 5 V, T _A = 25 °C		650		nA
		RTC w/ 32.768 kHz Crystal, VREGIN = 5 V, T _A = 25 °C		950	_	nA
VIOHD Current (High-drive I/O dis-	I _{VIOHD}	HV Mode (default)	_	2.5	5	μA
abled)		LV Mode	_	2	_	nA

Notes:

1. Perhipheral currents drop to zero when peripheral clock and peripheral are disabled, unless otherwise noted.

 Currents are additive. For example, where I_{DD} is specified and the mode is not mutually exclusive, enabling the functions increases supply current by the specified amount.

3. Includes all peripherals that cannot have clocks gated in the Clock Control module.

- 4. Includes supply current from internal regulator and PLL0OSC (>20 MHz) or LPOSC0 (<=20 MHz).
- 5. Flash execution numbers use 2 wait states for 80 MHz and 0 wait states at 20 MHz or less.
- 6. RAM execution numbers use 0 wait states for all frequencies.
- 7. IDAC output current and IVC input current not included.

8. Bias current only. Does not include dynamic current from oscillator running at speed.



Table 3.2. Power Consumption (Continued)

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
External Oscillator (EXTOSC0) ⁸	IEXTOSC	FREQCN = 111		3.8	4.7	mA
		FREQCN = 110		840	950	μA
		FREQCN = 101		185	220	μA
		FREQCN = 100		65	80	μA
		FREQCN = 011		25	30	μA
		FREQCN = 010		10	15	μA
		FREQCN = 001		5	10	μA
		FREQCN = 000		3	8	μA
SARADC0, SARADC1	I _{SARADC}	Sampling at 1 Msps, highest power mode settings.	_	1.2	1.5	mA
		Sampling at 250 ksps, lowest power mode settings.		390	510	μA
Temperature Sensor	I _{TSENSE}			75	105	μA
Internal SAR Reference	IREFFS	Normal Power Mode		680	750	μA
		Low Power Mode		160	190	μA
VREF0	I _{REFP}			75	100	μA
Comparator 0 (CMP0),	I _{CMP}	CMPMD = 11		0.5		μA
Comparator 1 (CMP1)		CMPMD = 10		3		μA
		CMPMD = 01		10		μA
		CMPMD = 00		25	_	μA
Capacitive Sensing (CAPSENSE0)	I _{CS}	Continuous Conversions		55	80	μA
IDAC0 ⁷ , IDAC1 ⁷	I _{IDAC}		—	75	90	μΑ
IVC0 ⁷	I _{IVC}	$I_{IN} = 0$		1.5	2.5	μA
Voltage Supply Monitor (VMON0)	I _{VMON}			15	25	μA

Notes:

1. Perhipheral currents drop to zero when peripheral clock and peripheral are disabled, unless otherwise noted.

 Currents are additive. For example, where I_{DD} is specified and the mode is not mutually exclusive, enabling the functions increases supply current by the specified amount.

- 3. Includes all peripherals that cannot have clocks gated in the Clock Control module.
- 4. Includes supply current from internal regulator and PLL0OSC (>20 MHz) or LPOSC0 (<=20 MHz).
- 5. Flash execution numbers use 2 wait states for 80 MHz and 0 wait states at 20 MHz or less.
- 6. RAM execution numbers use 0 wait states for all frequencies.
- 7. IDAC output current and IVC input current not included.
- 8. Bias current only. Does not include dynamic current from oscillator running at speed.



Table 3.4. Reset and Supply Monitor

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
V _{DD} High Supply Monitor Threshold	V _{VDDMH}	Early Warning	2.10	2.20	2.30	V
(VDDHITHEN = 1)		Reset	1.95	2.05	2.1	V
V _{DD} Low Supply Monitor Threshold	V_{VDDML}	Early Warning	1.81	1.85	1.88	V
(VDDHITHEN = 0)		Reset	1.70	1.74	1.77	V
V _{REGIN} Supply Monitor Threshold	V _{VREGM}	Early Warning	4.2	4.4	4.6	V
Power-On Reset (POR) Threshold	V _{POR}	Rising Voltage on V_{DD}		1.4	—	V
		Falling Voltage on V_{DD}	0.8	1	1.3	V
V _{DD} Ramp Time	t _{RMP}	Time to $V_{DD} \ge 1.8 V$	10		3000	μs
Reset Delay from POR	t _{POR}	Relative to V _{DD} ≥ V _{POR}	3		100	ms
Reset Delay from non-POR source	t _{RST}	Time between release of reset source and code execution	—	10		μs
RESET Low Time to Generate Reset	t _{RSTL}		50		_	ns
Missing Clock Detector Response Time (final rising edge to reset)	t _{MCD}	F _{AHB} > 1 MHz		0.4	1	ms
Missing Clock Detector Trigger Frequency	F _{MCD}			7.5	13	kHz
V _{DD} Supply Monitor Turn-On Time	t _{MON}		_	2		μs



Table 3.12. Capacitive Sense

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Single Conversion Time	t _{single}	12-bit Mode	—	25		μs
(Default Configuration)		13-bit Mode	—	27		μs
		14-bit Mode	—	29	_	μs
		16-bit Mode	—	33	_	μs
Maximum External Capacitive Load	CL	Highest Gain Setting (default)		45	—	pF
		Lowest Gain Setting		500		pF
Maximum External Series Impedance	CL	Highest Gain Setting (default)		50	—	kΩ

Table 3.13. Current-to-Voltage Converter (IVC)

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Supply Voltage (VDD)	V _{DDIVC}		2.2	—	3.6	V
Input Pin Voltage	V _{IN}		2.2		VDD	V
Minimum Input Current (source)	I _{IN}		100		—	μA
Integral Nonlinearity	INL _{IVC}		-0.6		0.6	%
Full Scale Output	VIVCOUT			1.65		V
Slope	M _{IVC}	Input Range 1 mA (INxRANGE = 101)	1.55	1.65	1.75	V/mA
		Input Range 2 mA (INxRANGE = 100)	795	830	860	mV/mA
		Input Range 3 mA (INxRANGE = 011)	525	550	570	mV/mA
		Input Range 4 mA (INxRANGE = 010)	390	415	430	mV/mA
		Input Range 5 mA (INxRANGE = 001)	315	330	340	mV/mA
		Input Range 6 mA (INxRANGE = 000)	260	275	285	mV/mA
Settling Time to 0.1%	VIVCOUT				500	ns



Table 3.16. Comparator (Continued)

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Positive Hysteresis Mode 3 (CPMD = 11)	HYS _{CP+}	CMPHYP = 00	—	1.4	—	mV
		CMPHYP = 01	—	4	—	mV
		CMPHYP = 10	—	8	—	mV
		CMPHYP = 11	_	16	_	mV
Negative Hysteresis	HYS _{CP-}	CMPHYN = 00	—	1.4	—	mV
Mode 3 (CPMD = 11)		CMPHYN = 01	—	-4	—	mV
		CMPHYN = 10	_	-8	_	mV
		CMPHYN = 11	_	-16	_	mV
Input Range (CP+ or CP-)	V _{IN}		-0.25	_	V _{DD} +0.25	V
Input Pin Capacitance	C _{CP}	PB2 Pins	_	7.5	_	pF
		PB3 Pins	_	10.5	—	pF
Common-Mode Rejection Ratio	CMRR _{CP}		—	75	—	dB
Power Supply Rejection Ratio	PSRR _{CP}		—	72	—	dB
Input Offset Voltage	V _{OFF}		-10	0	10	mV
Input Offset Tempco	TC _{OFF}		_	3.5	—	µV/°C
Reference DAC Resolution	N _{Bits}			6		bits



Table 3.17. Port I/O (Continued)

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
P-Channel Source Current Limit	I _{SRCL}	Mode 0	_	0.8		mA
$(2.7 \text{ V} \leq \text{VIOHD} \leq 6 \text{ V},$		Mode 1		1.25		-
V _{OH} = VIOHD – 0.8 V)	-	Mode 2		1.75		-
See Figure 3.2	-	Mode 3		2.5		-
		Mode 4		3.5		-
		Mode 5		4.75		-
		Mode 6		7		-
		Mode 7	_	9.5		-
		Mode 8	_	14		-
		Mode 9	_	18.75		-
		Mode 10	_	28.25	_	-
		Mode 11	_	37.5		-
		Mode 12	_	56.25		-
		Mode 13	_	75	_	-
		Mode 14	_	112.5	_	-
		Mode 15	_	150	_	-
Total P-Channel Source Current on P4.0-P4.5 (DC)	I _{SRCLT}		_	_	400	mA
Pin Capacitance	C _{IO}		_	30		pF
Weak Pull-Up Current in Low Volt- age Mode	I _{PU}	V _{IOHD} = 1.8 V	-6	-3.5	-2	μA
		V _{IOHD} = 3.6 V	-30	-20	-10	μA
Weak Pull-Up Current in High Volt- age Mode	I _{PU}	V _{IOHD} = 2.7 V	-15	-10	-5	μA
		V _{IOHD} = 6 V	-30	-20	-10	μA
Input Leakage (Pullups off)	I _{LK}		-1	_	1	μA
*Note: RESET does not drive to logic h	igh. Specific	cations for RESET V _{OL} adhe	ere to the low d	rive setting.		



3.2. Thermal Conditions

Table 3.18. Thermal Conditions

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit		
Thermal Resistance*	θ_{JA}	LGA-92 Packages		35		°C/W		
		TQFP-80 Packages		40		°C/W		
		QFN-64 Packages		25		°C/W		
		TQFP-64 Packages		30		°C/W		
		QFN-40 Packages		30		°C/W		
*Note: Thermal resistance assumes a multi-layer PCB with any exposed pad soldered to a PCB pad.								

3.3. Absolute Maximum Ratings

Stresses above those listed under Table 3.19 may cause permanent damage to the device. This is a stress rating only and functional operation of the devices at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

Table 3.19. Absolute Maximum Ratings

Parameter	Symbol	Test Condition	Min	Max	Unit
Ambient Temperature Under Bias	T _{BIAS}		-55	125	°C
Storage Temperature	T _{STG}		-65	150	°C
Voltage on VDD	V _{DD}		V _{SS} –0.3	4.2	V
Voltage on VREGIN	V _{REGIN}	EXTVREG0 Not Used	V _{SS} –0.3	6.0	V
		EXTVREG0 Used	V _{SS} –0.3	3.6	V
Voltage on VIO	V _{IO}		V _{SS} –0.3	4.2	V
Voltage on VIOHD	V _{IOHD}		V _{SS} –0.3	6.5	V
Voltage on I/O pins,	V _{IN}	RESET, V _{IO} ≥ 3.3 V	V _{SS} –0.3	5.8	V
		RESET, V _{IO} < 3.3 V	V _{SS} –0.3	V _{IO} +2.5	V
		Port Bank 0, 1, and 2 I/O	V _{SS} -0.3	V _{IO} +0.3	V
		Port Bank 4 I/O	V _{SSHD} -0.3	V _{IOHD} +0.3	V
	4	·			·

*Note: VSS and VSSHD provide separate return current paths for device supplies, but are not isolated. They must always be connected to the same potential on board.



Parameter	Symbol	Test Condition	Min	Max	Unit
Voltage on I/O pins, Port Bank 3 I/O	V _{IN}	SiM3C1x7, PB3.0– PB3.7, V _{IO} ≥ 3.3 V	V _{SS} -0.3	5.8	V
		SiM3C1x7, PB3.0– PB3.7, V _{IO} < 3.3 V	V _{SS} -0.3	V _{IO} +2.5	V
		SiM3C1x7, PB3.8 - PB3.11	V _{SS} -0.3	Lowest of V _{IO} +2.5, V _{REGIN} +0.3, or 5.8	V
		SiM3C1x6, PB3.0– PB3.5, V _{IO} ≥ 3.3 V	V _{SS} -0.3	5.8	V
		SiM3C1x6, PB3.0– PB3.5, V _{IO} < 3.3 V	V _{SS} -0.3	V _{IO} +2.5	V
		SiM3C1x6, PB3.6– PB3.9	V _{SS} -0.3	Lowest of V _{IO} +2.5, V _{REGIN} +0.3, or 5.8	V
		SiM3C1x4, PB3.0– PB3.3	V _{SS} -0.3	Lowest of V _{IO} +2.5, V _{REGIN} +0.3, or 5.8	V
Total Current Sunk into Supply Pins	I _{SUPP}	$V_{DD}, V_{REGIN}, V_{IO}, V_{IOHD}$	_	400	mA
Total Current Sourced out of Ground Pins	I _{VSS}	V _{SS,} V _{SSHD}	400	_	mA
Current Sourced or Sunk by Any I/O Pin	I _{PIO}	PB0, PB1 <u>, PB2,</u> PB3, and RESET	-100	100	mA
		PB4	-300	300	mA
Current Injected on Any I/O Pin	I _{INJ}	PB0, PB1 <u>, PB2,</u> PB3, and RESET	-100	100	mA
		PB4	-300	300	mA
Total Injected Current on I/O Pins	ΣΙ _{INJ}	Sum <u>of all I/O</u> and RESET	-400	400	mA
*Note: VSS and VSSHD provide separate connected to the same potential on	return curr board.	ent paths for device supplies,	but are not isol	ated. They must al	ways be



4.6. Communications Peripherals

4.6.1. External Memory Interface (EMIF0)

The External Memory Interface (EMIF0) allows external parallel asynchronous devices, like SRAMs and LCD controllers, to appear as part of the system memory map. The EMIF0 module includes the following features:

- Provides a memory mapped view of multiple external devices.
- Support for byte, half-word and word accesses regardless of external device data-width.
- Error indicator for certain invalid transfers.
- Minimum external timing allows for 3 clocks per write or 4 clocks per read.
- Output bus can be shared between non-muxed and muxed devices.
- Available extended address output allows for up to 24-bit address with 8-bit parallel devices.
- Support for 8-bit and 16-bit (muxed-mode only) devices with up to two chip-select signals.
- Support for internally muxed devices with dynamic address shifting.
- Fully programmable control signal waveforms.

4.6.2. USART (USART0, USART1)

The USART uses two signals (TX and RX) and a predetermined fixed baud rate to communicate with a single device. In addition to these signals, the USART0 module can optionally use a clock (UCLK) or hardware handshaking (RTS and CTS).

The USART module provides the following features:

- Independent transmitter and receiver configurations with separate 16-bit baud rate generators.
- Synchronous or asynchronous transmissions and receptions.
- Clock master or slave operation with programmable polarity and edge controls.
- Up to 5 Mbaud (synchronous or asynchronous, TX or RX, and master or slave) or 1 Mbaud Smartcard (TX or RX).
- Individual enables for generated clocks during start, stop, and idle states.
- Internal transmit and receive FIFOs with flush capability and support for byte, half-word, and word reads and writes.
- Data bit lengths from 5 to 9 bits.
- Programmable inter-packet transmit delays.
- Auto-baud detection with support for the LIN SYNC byte.
- Automatic parity generation (with enable).
- Automatic start and stop generation (with separate enables).
- Transmit and receive hardware flow-control.
- Independent inversion correction for TX, RX, RTS, and CTS signals.
- IrDA modulation and demodulation with programmable pulse widths.
- Smartcard ACK/NACK support.
- Parity error, frame error, overrun, and underrun detection.
- Multi-master and half-duplex support.
- Multiple loop-back modes supported.
- Multi-processor communications support.

4.6.3. UART (UART0, UART1)

The USART uses two signals (TX and RX) and a predetermined fixed baud rate to communicate with a single device.

The UART module provides the following features:

- Independent transmitter and receiver configurations with separate 16-bit baud-rate generators.
- Asynchronous transmissions and receptions.
- Up to 5 Mbaud (TX or RX) or 1 Mbaud Smartcard (TX or RX).



- Internal transmit and receive FIFOs with flush capability and support for byte, half-word, and word reads and writes.
- Data bit lengths from 5 to 9 bits.
- Programmable inter-packet transmit delays.
- Auto-baud detection with support for the LIN SYNC byte.
- Automatic parity generation (with enable).
- Automatic start and stop generation.
- Transmit and receive hardware flow-control.
- Independent inversion correction for TX, RX, RTS, and CTS signals.
- IrDA modulation and demodulation with programmable pulse widths.
- Smartcard ACK/NACK support.
- Parity error, frame error, overrun, and underrun detection.
- Multi-master and half-duplex support.
- Multiple loop-back modes supported.

4.6.4. SPI (SPI0, SPI1)

SPI is a 3- or 4-wire communication interface that includes a clock, input data, output data, and an optional select signal.

The SPI module includes the following features:

- Supports 3- or 4-wire master or slave modes.
- Supports up to 10 MHz clock in master mode and 5 MHz clock in slave mode.
- Support for all clock phase and slave select (NSS) polarity modes.
- 16-bit programmable clock rate.
- Programmable MSB-first or LSB-first shifting.
- 8-byte FIFO buffers for both transmit and receive data paths to support high speed transfers.
- Programmable FIFO threshold level to request data service for DMA transfers.
- Support for multiple masters on the same data lines.

4.6.5. I2C (I2C0, I2C1)

The I2C interface is a two-wire, bi-directional serial bus. The two clock and data signals operate in open-drain mode with external pull-ups to support automatic bus arbitration.

Reads and writes to the interface are byte oriented with the I2C interface autonomously controlling the serial transfer of the data. Data can be transferred at up to 1/8th of the APB clock as a master or slave, which can be faster than allowed by the I2C specification, depending on the clock source used. A method of extending the clock-low duration is available to accommodate devices with different speed capabilities on the same bus.

The I2C interface may operate as a master and/or slave, and may function on a bus with multiple masters. The I2C provides control of SDA (serial data), SCL (serial clock) generation and synchronization, arbitration logic, and start/ stop control and generation.

The I2C module includes the following features:

- Standard (up to 100 kbps) and Fast (400 kbps) transfer speeds.
- Can operate down to APB clock divided by 32768 or up to APB clock divided by 8.
- Support for master, slave, and multi-master modes.
- Hardware synchronization and arbitration for multi-master mode.
- Clock low extending (clock stretching) to interface with faster masters.
- Hardware support for 7-bit slave and general call address recognition.
- Firmware support for 10-bit slave address decoding.
- Ability to disable all slave states.
- Programmable clock high and low period.
- Programmable data setup/hold times.



4.7. Analog

4.7.1. 12-Bit Analog-to-Digital Converters (SARADC0, SARADC1)

The SARADC0 and SARADC1 modules on SiM3C1xx devices are Successive Approximation Register (SAR) Analog to Digital Converters (ADCs). The key features of the SARADC module are:

- Single-ended 12-bit and 10-bit modes.
- Supports an output update rate of 250 k samples per second in 12-bit mode or 1 M samples per second in 10-bit mode.
- Operation in low power modes at lower conversion speeds.
- Selectable asynchronous hardware conversion trigger with hardware channel select.
- Output data window comparator allows automatic range checking.
- Support for Burst Mode, which produces one set of accumulated data per conversion-start trigger with programmable power-on settling and tracking time.
- Conversion complete, multiple conversion complete, and FIFO overflow and underflow flags and interrupts supported.
- Flexible output data formatting.
- Sequencer allows up to 8 sources to be automatically scanned using one of four channel characteristic profiles without software intervention.
- Eight-word conversion data FIFO for DMA operations.
- Multiple SARADC modules can work together synchronously or by interleaving samples.
- Includes two internal references (1.65 V fast-settling, 1.2/2.4 V precision), support for an external reference, and support for an external signal ground.

4.7.2. Sample Sync Generator (SSG0)

The SSG module includes a phase counter and a pulse generator. The phase counter is a 4-bit free-running counter clocked from the SARADC module clock. Counting-up from zero, the phase counter marks sixteen equally-spaced events for any number of SARADC modules. The ADCs can use this phase counter to start a conversion. The programmable pulse generator creates a 50% duty cycle pulse with a period of 16 phase counter ticks. Up to four programmable outputs available to external devices can be driven by the pulse generator with programmable polarity and a defined output setting when the pulse generator is stopped.

The Sample Sync Generator module has the following features:

- Connects multiple modules together to perform synchronized actions.
- Outputs a clock synchronized to the internal sampling clock used by any number of SARADC modules to pins for use by external devices.
- Includes a phase counter, pulse generator, and up to four programmable outputs.

4.7.3. 10-Bit Digital-to-Analog Converter (IDAC0, IDAC1)

The IDAC takes a digital value as an input and outputs a proportional constant current on a pin. The IDAC module includes the following features:

- 10-bit current DAC with support for four timer, up to seven external I/O, on demand, and SSG0 output update triggers.
- Ability to update on rising, falling, or both edges for any of the external I/O trigger sources (DACnTx).
- Supports an output update rate greater than 600 k samples per second.
- Support for three full-scale output modes: 0.5 mA, 1.0 mA and 2.0 mA.
- Four-word FIFO to aid with high-speed waveform generation or DMA interactions.
- Individual FIFO overrun, underrun, and went-empty interrupt status sources.
- Support for multiple data packing formats, including: single 10-bit sample per word, dual 10-bit samples per word, or four 8-bit samples per word.
- Support for left- and right-justified data.



4.8. Reset Sources

Reset circuitry allows the controller to be easily placed in a predefined default condition. On entry to this reset state, the following occur:

- The core halts program execution.
- Module registers are initialized to their defined reset values unless the bits reset only with a power-on reset.
- External port pins are forced to a known state.
- Interrupts and timers are disabled.
- Clocks to all AHB peripherals are enabled.
- Clocks to all APB peripherals other than Watchdog Timer, EMIF0, and DMAXBAR are disabled.

All registers are reset to the predefined values noted in the register descriptions unless the bits only reset with a power-on reset. The contents of RAM are unaffected during a reset; any previously stored data is preserved as long as power is not lost.

The Port I/O latches are reset to 1 in open-drain mode. Weak pullups are enabled during and after the reset. For VDD Supply Monitor and power-on resets, the RESET pin is driven low until the device exits the reset state.

On exit from the reset state, the program counter (PC) is reset, and the system clock defaults to an internal oscillator. The Watchdog Timer is enabled with the Low Frequency Oscillator (LFO0) as its clock source. Program execution begins at location 0x00000000.





Pin Name	Туре	Pin Numbers TQFP-80	Pin Numbers LGA-92	Crossbar Capability (see Port Config Section)	Port Match	External Memory Interface (m = muxed mode)	Port-Mapped Level Shifter	Output Toggle Logic	External Trigger Inputs	Analog or Additional Functions
PB4.0	High Drive I/O	8	A6				LSO0			
PB4.1	High Drive I/O	7	A5				LSO1			
PB4.2	High Drive I/O	6	A4				LSO2			
PB4.3	High Drive I/O	3	A2				LSO3			
PB4.4	High Drive I/O	2	A1				LSO4			
PB4.5	High Drive I/O	1	D1				LSO5			
Note: All unnamed pins on the LGA-92 package are no-connect pins. They should be soldered to the PCB for mechanical stabil- ity, but have no internal connections to the device.										

Table 6.1. Pin Definitions and alternate functions for SiM3C1x7 (Continued)



Pin Name	Туре	Pin Numbers	Crossbar Capability (see Port Config Section)	Port Match	External Memory Interface (m = muxed mode)	Port-Mapped Level Shifter	Output Toggle Logic	External Trigger Inputs	Analog or Additional Functions
PB3.2	5 V Tolerant I/O	14	XBR1	~	AD0m/ D0			DAC0T0 DAC1T0 LPT0T0 WAKE.8	CMP0P.2 CMP1P.2
PB3.3	5 V Tolerant I/O	13	XBR1	~	WR			DAC0T1 DAC1T1 INT0.4 INT1.4 WAKE.9	CMP0N.2 CMP1N.2
PB3.4	5 V Tolerant I/O	12	XBR1	~	ŌĒ			INT0.5 INT1.5 WAKE.10	CMP0P.3 CMP1P.3
PB3.5	5 V Tolerant I/O	11	XBR1	V	ALEm			DAC0T2 DAC1T2 INT0.6 INT1.6 WAKE.11	CMP0N.3 CMP1N.3
PB3.6	5 V Tolerant I/O	10	XBR1	~	CS0			DAC0T3 DAC1T3 INT0.7 INT1.7 WAKE.12	CMP0P.4 CMP1P.4 EXREGSP
PB3.7	5 V Tolerant I/O	9	XBR1	~	BE1			DAC0T4 DAC1T4 INT0.8 INT1.8 WAKE.13	CMP0N.4 CMP1N.4 EXREGSN
PB3.8	5 V Tolerant I/O	8	XBR1	~	CS1			DAC0T5 DAC1T5 LPT0T1 INT0.9 INT1.9 WAKE.14	CMP0P.5 CMP1P.5 EXREGOUT

Table 6.2. Pin Definitions and alternate functions for SiM3C1x6 (Continued)



Pin Name	Туре	Pin Numbers	Crossbar Capability (see Port Config Section)	Port Match	Output Toggle Logic	External Trigger Inputs	Analog or Additional Functions
PB0.8	Standard I/O	26	XBR0	~			ADC0.14 ADC1.14
PB0.9	Standard I/O	25	XBR0	~			ADC0.15 ADC1.15
PB0.10	Standard I/O	22	XBR0	\checkmark		DMA0T1	ADC1.8
PB0.11	Standard I/O	21	XBR0	\checkmark		DMA0T0	ADC1.7
PB0.12	Standard I/O	20	XBR0	~		ADC0T15 WAKE.0	ADC1.5 CS0.10
PB0.13	Standard I/O	19	XBR0	~		ADC1T15 WAKE.1	ADC1.4 CS0.11
PB0.14	Standard I/O	18	XBR0	~		WAKE.2	ADC1.3 CS0.12
PB0.15	Standard I/O	17	XBR0	~		WAKE.3	ADC1.2 CS0.13
PB1.0	Standard I/O	16	XBR0	V		WAKE.4	ADC1.1 CS0.14
PB1.1	Standard I/O	15	XBR0	\checkmark		WAKE.5	ADC1.0 CS0.15 PMU_Asleep
PB1.2	Standard I/O	12	XBR0	~			CMP0N.0 CMP1N.0 RTC0TCLK_OUT
PB1.3	Standard I/O	11	XBR0	V			CMP0P.0 CMP1P.0
PB3.0	5 V Tolerant I/O	10	XBR1	V		DAC0T0 DAC1T0 LPT0T0 INT0.0 INT1.0 WAKE.12	CMP0P.1 CMP1P.1 EXREGSP

Table 6.3. Pin Definitions and Alternate Functions for SiM3C1x4 (Continued)





6.6. QFN-64 Package Specifications



Dimension	Min	Nominal	Max				
Α	0.80	0.85	0.90				
A1	0.00	0.02	0.05				
b	0.18	0.18 0.25 0.30					
D		9.00 BSC					
D2	3.95	4.10	4.25				
е	0.50 BSC						
E	9.00 BSC						
E2	3.95	4.10	4.25				
L	0.30	0.40	0.50				
aaa	0.10						
bbb	0.10						
CCC	0.08						
ddd		0.10					
eee		0.05					
	÷						

Table 6.8. QFN-64 Package Dimensions

Notes:

1. All dimensions shown are in millimeters (mm) unless otherwise noted.

2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.

3. This package outline conforms to JEDEC MO-220.

4. Recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.



6.7. TQFP-64 Package Specifications



Figure 6.12. TQFP-64 Package Drawing

Dimension	Min	Nominal	Max			
Α	—	—	1.20			
A1	0.05	—	0.15			
A2	0.95	1.00	1.05			
b	0.17	0.22	0.27			
С	0.09	—	0.20			
D	12.00 BSC					
D1	10.00 BSC					
е	0.50 BSC					
E	12.00 BSC					
E1	10.00 BSC					
L	0.45	0.60	0.75			
Θ	0°	3.5°	7°			

Table 6.10. TQFP-64 Package Dimensions





Figure 6.13. TQFP-64 Landing Diagram

 Table 6.11. TQFP-64 Landing Diagram Dimensions

Dimension	Min	Мах			
C1	11.30	11.40			
C2	11.30	11.40			
E	0.50 BSC				
X	0.20	0.30			
Y	1.40	1.50			
 Notes: 1. All dimensions shown are in millimeters (mm) unless otherwise noted. 2. This land pattern design is based on the IPC-7351 guidelines. 					



DOCUMENT CHANGE LIST

Revision 0.8 to Revision 1.0

- Added block diagram to front page; updated feature bullet lists.
- Electrical Specifications Tables Additions:
 - Voltage Regulator Current Sense Supply Current, Typ = $3 \mu A$ (Table 3.2)
 - Power Mode 2 Wake Time, Min = 4 clocks, Max = 5 clocks (Table 3.3)
 - External Crystal Clock Frequency, Min = 0.01 MHz, Max = 30 MHz (Table 3.9)
 - Added /RESET pin characteristics (Table 3.17)
- Electrical Specifications Tables Removals:
 - Power Mode 3 Wake Time (Table 3.3)
- Electrical Specifications Tables Corretions/Adjustments:
 - IVC Supply Current, Max = 2.5 μA (Table 3.2)
 - VREG0 Output Voltage Normal Mode, Min = 3.15 V (Table 3.5)
 - VREG0 Output Voltage Suspend Mode, Min = 3.15 V (Table 3.5)
 - External Regulator Internal Pull-Down, Typ = $5 \text{ k}\Omega$ (Table 3.6)
 - External Regulator Internal Pull-Up, Typ = 10 k Ω (Table 3.6)
 - Flash Memory Endurance, Typ = 100k write/erase cycles (Table 3.7)
 - Flash Memory Retention, Min = 10 Years, Typ = 100 Years (Table 3.7)
 - Low Power Oscillator Frequency, Min = 19.5 MHz, Max = 20.5 MHz (Table 3.8)
 - SAR Dynamic Performance : consolidated all specs. (Table 3.10)
 - IDAC Full Scale Output Current 1 mA Range, Min = 0.99 mA (Table 3.11)
 - IDAC Full Scale Output Current 0.5 mA Range, Min = 493 μA (Table 3.11)
 - IVC Slope @ 1 mA, Min = 1.55 V/mA, Max = 1.75 V/mA (Table 3.13)
 - IVC Slope @ 2 mA, Min = 795 mV/mA, Max = 860 mV/mA (Table 3.13)
 - IVC Slope @ 3 mA, Min = 525 mV/mA, Max = 570 mV/mA (Table 3.13)
 - IVC Slope @ 4 mA, Min = 390 mV/mA, Max = 430 mV/mA (Table 3.13)
 - IVC Slope @ 5 mA, Min = 315 mV/mA (Table 3.13)
 - IVC Slope @ 6 mA, Min = 260 mV/mA (Table 3.13)
 - Temperature Sensor Slope Error, Type = $\pm 120 \,\mu$ V/C (Table 3.15)
 - Comparator Input Offset Voltage, Min = -10 mV, Max = 10 mV (Table 3.16)
- "4. Precision32TM SiM3C1xx System Overview":
 - Updated Power Modes discussion.
 - Refined and updated feature bullet lists.
- Updated and clarified RTC timer clock output. The RTC output is now referred to as "RTC0TCLK".
- "6. Pin Definitions and Packaging Information": Renamed RTC0OSC_OUT function to RTC0TCLK_OUT for consistency.
- "7. Revision Specific Behavior": Updated revision identification drawings to better match physical appearance of packages.

